A Low-loss Wideband Filtering Coupler with Patterned Substrate Integrated Suspended Line (SISL) Technology

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Abstract — A wideband filter-integrated coupler has been presented using the substrate integrated suspended line structure with patterned substrate. This coupler is composed of a two-line coupled line, two variant coupled lines, and four three-line coupled lines at each port. The SISL structure is composed of five print circuit boards, connected together by metal via holes. There is a hollowed substrate between two air cavities to reduce the loss. For further explanation, two wideband filtering SISL couplers operating at different operating frequencies with equal/unequal power divisions are designed and simulated, of which a specific coupler working at 1.66 GHz with a relative bandwidth of about 52.56% is fabricated and measured. The experimental results agree well with the theoretical and simulation ones. This proposed coupler has many advantages such as self-packaged, low loss, filter integration, arbitrary power division ratio, and inherent DC-block function.

Index Terms — Filtering coupler, microwave components, patterned substrate, substrate integrated suspended line (SISL), wide band.

I. INTRODUCTION

Branch-line coupler (BLC) has become an essential part in the RF/microwave circuits and systems, which has found a wide utilization in balanced power amplifier [1], balanced mixer [2], and frequency discriminator [3]. Nowadays, with the rapid development of 5G and satellite communication, multiple-antenna systems, such as isophoric sparse arrays [4] and massive MIMO arrays [5], have brought forward higher requirements on the feed network of antenna and antenna array. As a critical part of the feed network, BLC has been used for Butler matrix for beam forming network [6], exciting multiple modes of the multimode multi-element antenna [7], and so on. Thus, multi-function integration, such as filtering, power splitting/combing, unequal power-division ratio, flatness of amplitude and phase differences, has been more and more important for application, among which the filtering-integrated coupler has attracted more and more interests of researchers. The conventional method to realize filtering function is cascading filtering units with the coupler, for example, reference [8] uses net-type resonator to construct a rat-race coupler with bandpass response, and reference [9] utilized coupled resonator to design the filtering 180° hybrid. Recently, other technologies like substrate integrated waveguide (SIW) [10] and low temperature co-fired ceramic (LTCC) [11] are also introduced into the design of filtering coupler. But the aforementioned design methods cannot realize broad bandwidth, filtering function and low loss property at the same time.

The substrate integrated suspended line (SISL) structures [12-13] are composed of multi-layer print circuit boards. There are two air cavities on both sides of the core circuit, so the field of the circuit is mainly distributed in the air. Besides, the substrate of the core circuit is hollowed with specific shape. Thus, both the dielectric loss and the radiation loss of the suspended line are relatively smaller than the ones of microstrip line (ML) and strip line. In [12], a novel compact branch-line coupler has been designed using the SISL technology, and in [13], SISL and double-sided SISL (DSISL) inductors with patterned substrate are proposed. Compared with conventional metal-cavity structure, SISL technology has solved many problems, showing an excellent performance on cost, weight, support of the substrate, and so on.

In this paper, a wideband filter-integrated coupler using substrate integrated suspended line (SISL) technology has been designed, simulated, and fabricated. As an expansion of the authors’ previous work in [14], we chose two specific couplers as examples to further explain the design and advantages of the SISL coupler. This coupler improved the origin transmission-line
structure in [15] for size reducing. Besides, with the help of the patterned SISL technology, loss can be narrowed. And the comparison of the losses between the proposed one and conventional one is also given. This low-loss SISL coupler can also realize filter integration, flexible power division ratio, and inherent DC-block function at the same time. Compared with the former work of the authors in [14], this work explains the design procedures in detail and provides two design examples with experimental result, in which the properties of this coupler such as low loss, flexible power division ratio, etc. have been verified. Besides, we discuss the influence of physical circuit parameters on the properties of the coupler and give the design procedures. The first SISL coupler named Example A works at 1.66 GHz with 7 dB power division, and the other named Example B is designed with 3.50 GHz operating frequency and equal power division. Both simulation and measured results coincide well with each other. Moreover, this low-loss wideband filtering BLC can be applied to many situations of wireless communication systems.

II. WIDEBAND FILTERING SISL COUPLER

The design method of the proposed wideband filter-integrated coupler can be divided into two parts. Firstly, we design and optimize the SISL structure according to the technology in [12]. Secondly, the basic circuit of the wideband filtering coupler is designed and discussed. Finally, we combine these two procedures together and take the overall simulation and optimization of the SISL coupler.

A. SISL structure

The SISL structure contains five double-side print circuit boards, which are fixed together by several screws as shown in Fig. 1. The five substrate layers, named as Substrate 1, 2, 3, 4, and 5, have created totally ten metal planes named as G1, G2, ..., G10 from top to bottom. Substrate 1 and 5 act as electromagnetism shields for the SISL structure, with G1, 2, 9, and 10 being ground planes. Substrate 2 and 4 provide two air cavities on the upper and lower of the suspended circuit. The air cavities are actually a kind of open slot of the substrate, which are surrounded by via holes. Substrate 3 acts as the suspended substrate. The basic circuit of the wideband filtering coupler, which would be discussed in the next part, is etched on G5. The field of the circuit on G5 is mainly distributed on the two air cavities on Substrate 2 and 4, with a boundary brought by the metal holes surrounding the air cavities. The dielectric of Substrate 3 possesses low loss tangent and is hollowed according to the shape of the coupler, thus both radiation loss and substrate loss can be greatly reduced [13].

B. Core circuit of the wideband filtering coupler

The primary circuit of the broadband filter-integrated coupler on G3 is shown in Fig. 2. The coupler has both horizontally and vertically symmetric layout, composed of one two-line coupled line in the center, two deformed coupled lines at the top and bottom sides, and four three-line coupled lines connected to the ports. The coupler can also achieve wideband filtering function, inherent DC-block between the ports, and unequal power division. The power division ratio can be altered by tuning w1 and w2. For further explanation, two design examples with different design requirements have been designed and simulated.

Fig. 1. The SISL construction of the proposed coupler: (a) 3D layout and (b) cross section.

Fig. 2. The circuit configuration of the wideband filtering coupler.

III. DESIGN EXAMPLES

A. Example A

The first case of the SISL coupler named Example A works at 1.66 GHz with 7 dB power division, which
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has been discussed in [14]. The material of Substrate 1, 2, 4, and 5 is chosen as FR-4, with the dielectric constant \( \varepsilon_r \) being 4.4, the thickness \( h_1 \) being 1.5 mm, and loss tangent being 0.02. Substrate 3 is designed to be FR-4B, whose dielectric constant \( \varepsilon_r \) being 2.65, the thickness \( h_2 \) being 0.254 mm, and loss tangent being 0.001.

When designing the specific structure of the SISL coupler, we define the demands of the coupler first, namely operating frequency and power division ratio. The operating frequency of the coupler is related to the lengths of the coupled lines. When the working frequency of a specific coupler is determined, the lengths of \( l_1, l_2, l_3, \) and \( l_4 \) can be defined. Considering that the power division ratio is affected mainly by the width of \( w_1 \) and \( w_2 \), they can be determined by repeated simulations using ADS Momentum. Then other parameters will be chosen by the optimization of HFSS Optimetrics Analysis.

Then the physical parameters of the Example A can be defined as follows (with units of mm): \( w_1=1, l_1=3.5, l_2=3, s_1=2, s_2=2, w_3=5, l_3=30, s_3=0.2, w_4=1.4, l_4=33, s_4=0.2, w_c=33, l_c=8, w_1=35, l_1=19, w_2=85.8, l_2=52. \) The structure of Example A is illustrated in Fig. 3, in which the total configuration of the SISL structure is shown in Fig. 3 (a), while the circuit of the coupler is shown in Fig. 3 (b). The simulated results are given in Fig. 4 [14]. From these curves, we can see that this coupler can realize wideband filtering function and possesses flat phase difference. The relative bandwidth is about 52.56% with \( S_{11} \) lower than -15 dB.

![Fig. 3. The constructions of Example A. (a) The overall structure, and (b) the main circuit of the coupler on G3.](image)

![Fig. 4. The calculated results of Example A [14]. (a) The S-parameters, and (b) phase difference.](image)

The loss of the coupler can be defined as [12],

\[
Loss = 1 - |S_{11}|^2 - |S_{21}|^2 - |S_{31}|^2 - |S_{41}|^2 .
\]

(1)

Then we calculate the losses of the designed SISL coupler and conventional microstrip line coupler, which are shown in Fig. 5 [14] for comparison. As we can see, the SISL coupler has a lower loss than the microstrip line one.

The relationship between the power division ratio and the line width of \( w_1 \) and \( w_2 \) would be further discussed. As shown in Fig. 6, as the increasing of \( w_1 \), the power division ratio will decrease. While in Fig. 7, the variation trend of the power division ratio along with the line width \( w_2 \) is contrary to the one in Fig. 6. That is, the power division ratio increases with the increasing of the line width \( w_2 \).

B. Example B

When designing Example B, equal power division and higher operating frequencies are considered. The substrate and configuration of the multi-layer structure are chosen to be the same as those in Example A. The physical parameters of the Example B can be simulated and optimized by ADS Momentum and HFSS as follows.
(with units of mm): \( w_1 = 2.5, l_1 = 3, l_2 = 2, s_1 = 2, s_2 = 1.7, w_2 = 3.5, l_3 = 17, s_3 = 0.2, w_3 = 0.8, w_4 = 1.3, l_4 = 20, s_4 = 0.2, w_5 = 20, l_5 = 8, w_6 = 22, l_6 = 12.5, w_7 = 57.8, l_7 = 37.4 \). The SISL structure of the Example B is shown in Fig. 8 (a), while the circuit of the coupler is shown in Fig. 8 (b).

Fig. 5. The losses of SISL coupler and ML coupler [14].

Fig. 6. The power division ratios of the SISL coupler width varies \( w_1 \) when \( w_2 = 5 \) mm.

Fig. 7. The power division ratios of the SISL coupler width varies \( w_2 \) when \( w_1 = 1 \) mm.

Fig. 8. The constructions of Example B. (a) The overall structure, and (b) the main circuit of the coupler on \( G_3 \).

Fig. 9. The calculated results of Example B. (a) The S-parameters, and (b) phase difference.
The simulated scattering parameters and phase difference are shown in Figs. 9 (a) and (b), respectively. It can be observed that this coupler possesses a relative bandwidth of 54.28% with $S_{11}$ lower than -15 dB and a flat phase difference. So, the wideband filtering coupler has been realized.

IV. MEASURED RESULTS

In order to verify the performance of the SISL wideband filter-integrated coupler, we take Example A as an experimental case. The design parameters of the coupler are all the same as those explained in Section III.A. The photograph of the fabricated SISL coupler is illustrated in Fig. 10. The size of the coupler is about $110.2 \times 70 \times 6.254$ mm$^3$. Figures 11 (a) and (b) are the simulated and measured S-parameters and phase differences of the coupler in Example A, separately. As we can see from the figures, the coupler works at 1.66 GHz, with a power division of about 7 dB. The coupler has good matching and isolation and possesses a relative bandwidth of about 49.398% with $S_{11}$ lower than -15 dB. In addition, the major features and advantages of this SISL wideband filtering BLC compared with other reported ones are listed in Table 1.

V. CONCLUSION

In this paper, a compact wideband filter-integrated coupler is designed, simulated and fabricated using the patterned substrate integrated suspended line technology. The design and optimization procedures of the coupler have been explained in detail, and two cases with different operating frequencies of 1.66/3.5 GHz and unequal/equal power division ratios were designed as examples. The loss of the designed couplers was greatly reduced compared with that of traditional ones. Then for further verification, a specific SISL coupler working at 1.66 GHz with 7 dB power division and 52.56% relative bandwidth was designed and fabricated. The measured scattering parameters and phase difference coincided well with the theory and the simulated results. This coupler has the advantages such as self-package, low loss, filter integration, and flexible power division ratio, which is propitious to the applications in the microwave circuits and wireless communication systems.

Table 1: Performance comparison of the proposed SISL wideband filtering BLC with other reported ones

<table>
<thead>
<tr>
<th>Refs.</th>
<th>BW (%)</th>
<th>IL (dB)</th>
<th>Technology</th>
<th>Self-Packaged</th>
</tr>
</thead>
<tbody>
<tr>
<td>[8]</td>
<td>19%</td>
<td>1.38</td>
<td>PCB</td>
<td>No</td>
</tr>
<tr>
<td>[9]</td>
<td>10%</td>
<td>0.7</td>
<td>PCB</td>
<td>No</td>
</tr>
<tr>
<td>[10]</td>
<td>2.5%</td>
<td>1.9</td>
<td>SIW</td>
<td>No</td>
</tr>
<tr>
<td>[11]</td>
<td>8.6%</td>
<td>1.8</td>
<td>LTCC</td>
<td>Yes</td>
</tr>
<tr>
<td>This work</td>
<td>49.398%</td>
<td>0.655</td>
<td>SISL</td>
<td>Yes</td>
</tr>
</tbody>
</table>

*: with return loss < -15 dB.

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REFERENCES


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